

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# H7N0607DL, H7N0607DS

Silicon N Channel MOS FET  
High Speed Power Switching

REJ03G0124-0300

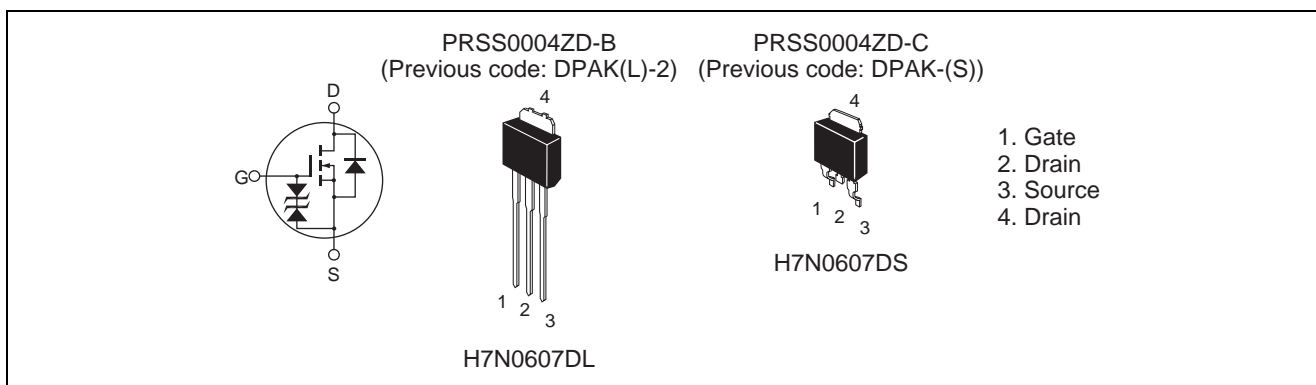
Rev.3.00

Jan.27.2005

## Features

- Low on-resistance  
 $R_{DS(on)} = 26 \text{ m}\Omega$  typ.
- Low drive current.
- Capable of 4.5 V gate drive

## Outline



## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Rating	Unit
Drain to source voltage	$V_{DSS}$	60	V
Gate to source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	$I_D$	20	A
Drain peak current	$I_D$ (pulse) <sup>Note1</sup>	80	A
Body drain diode reverse drain current	$I_{DR}$	20	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	8	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	5.48	mj
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	25	W
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10 \mu\text{s}$ , duty cycle  $\leq 1\%$

2.  $T_c = 25^\circ\text{C}$

3. Value at  $T_{ch} = 25^\circ\text{C}$ ,  $R_g \geq 50 \Omega$

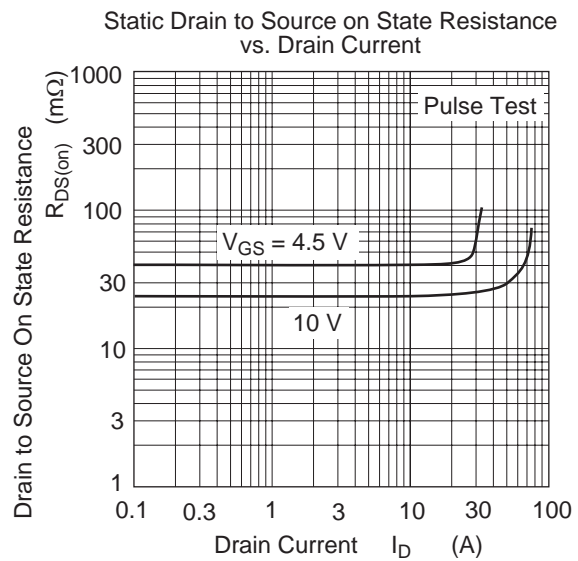
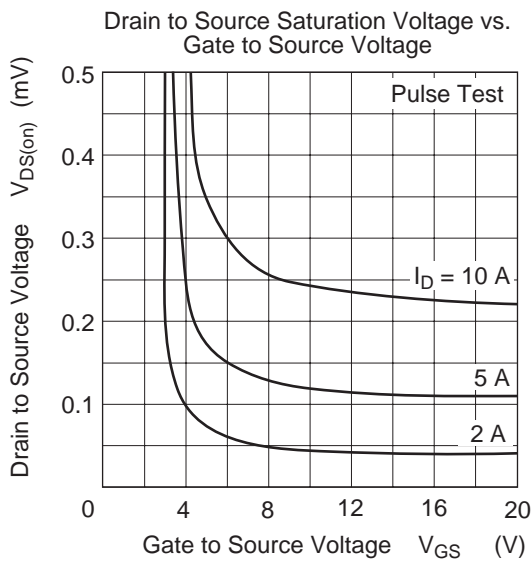
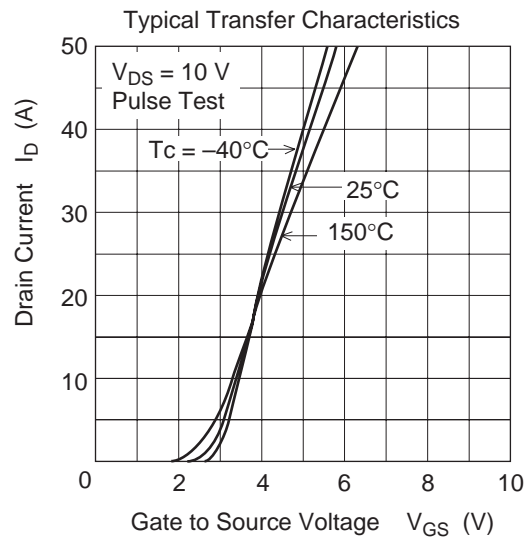
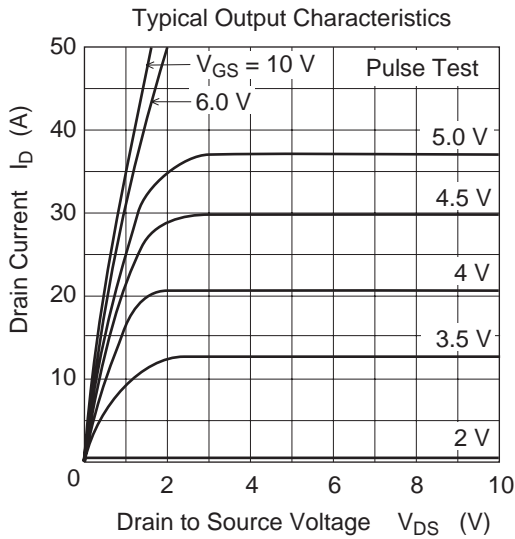
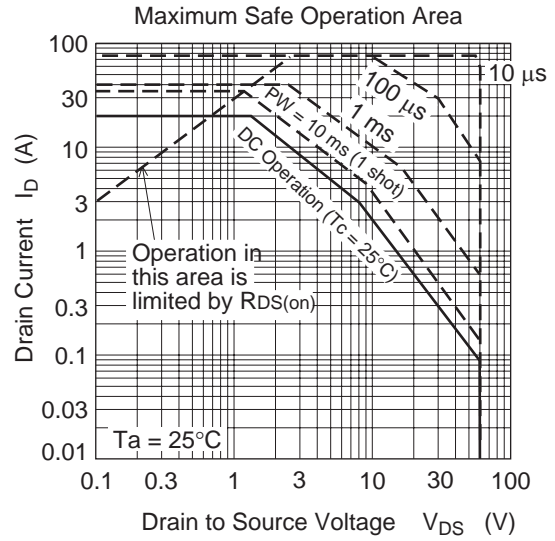
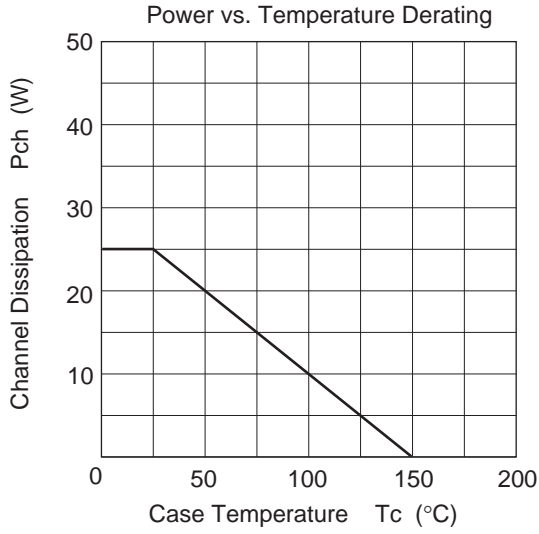
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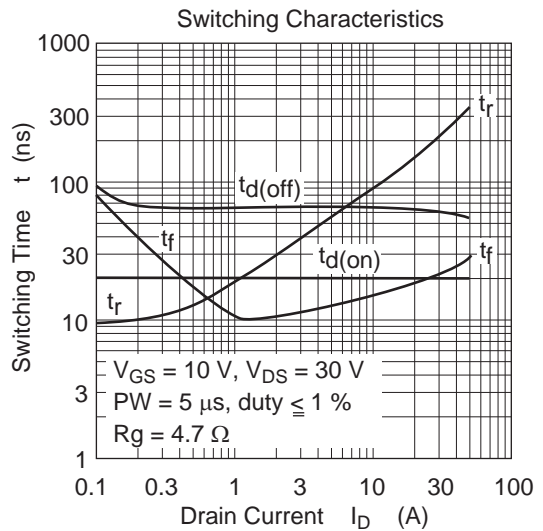
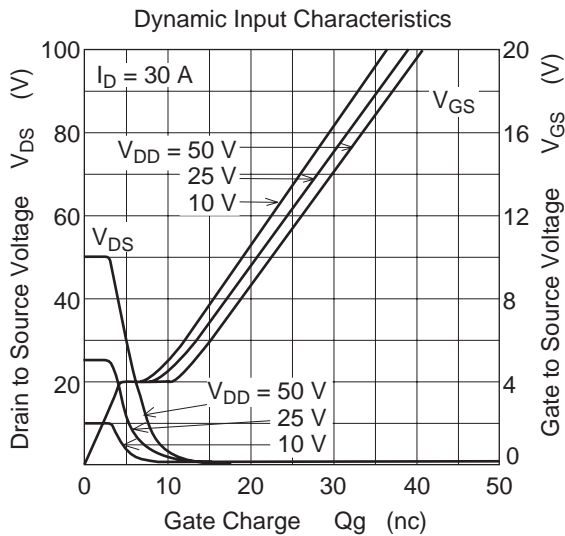
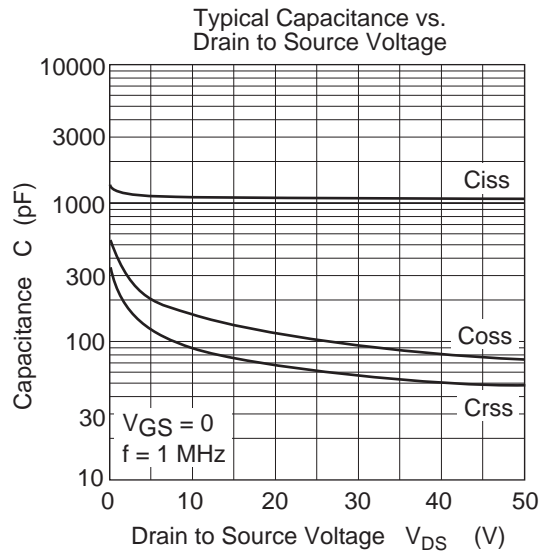
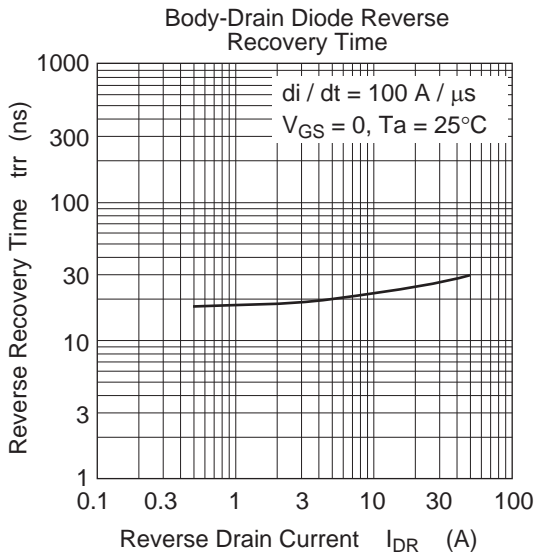
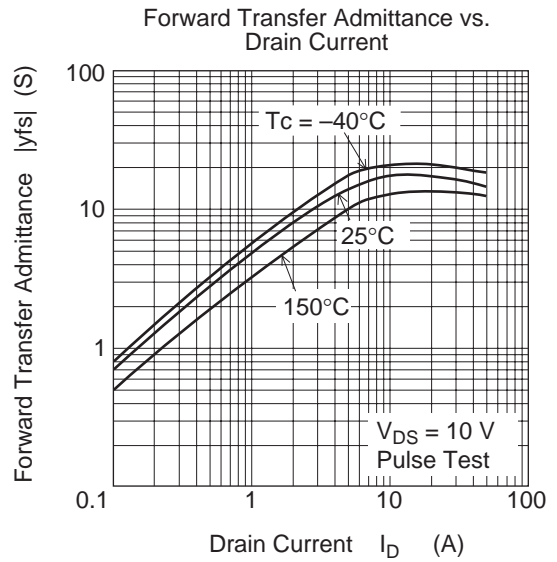
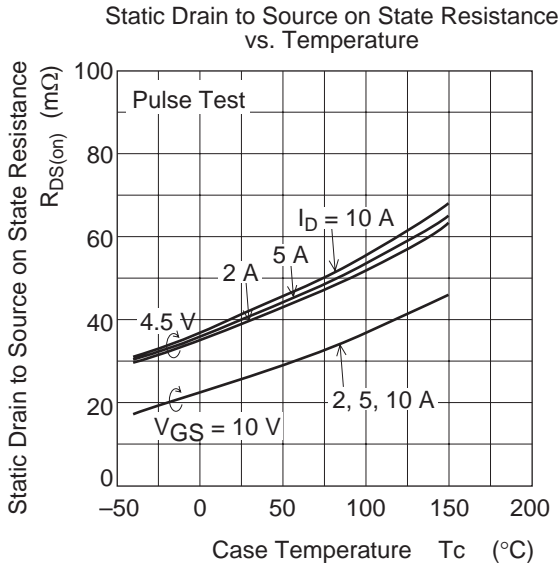
(Ta = 25°C)

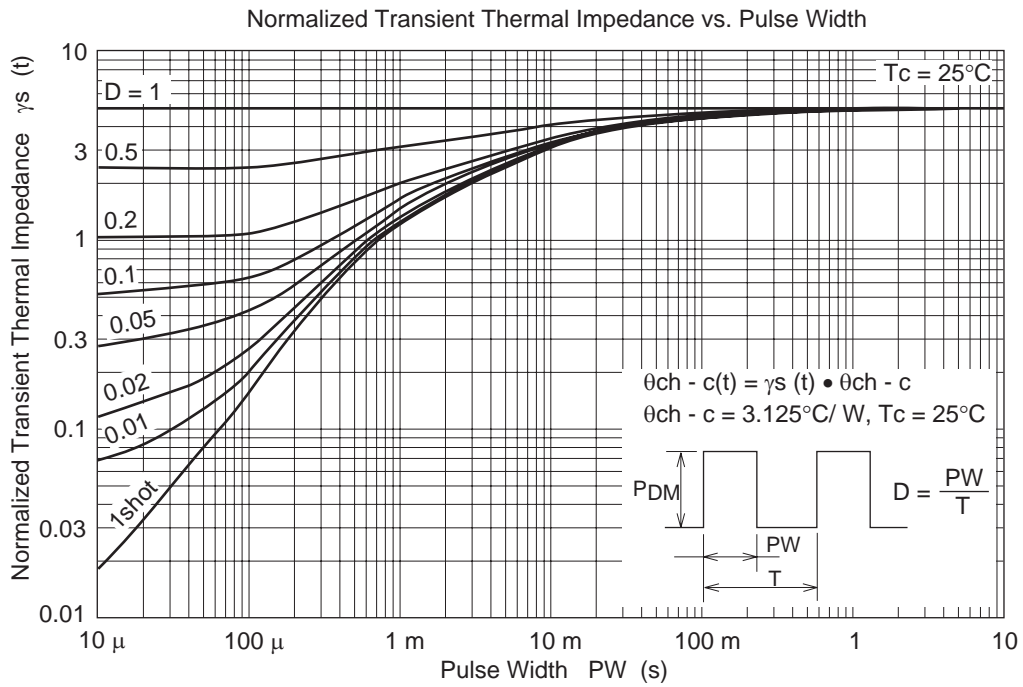
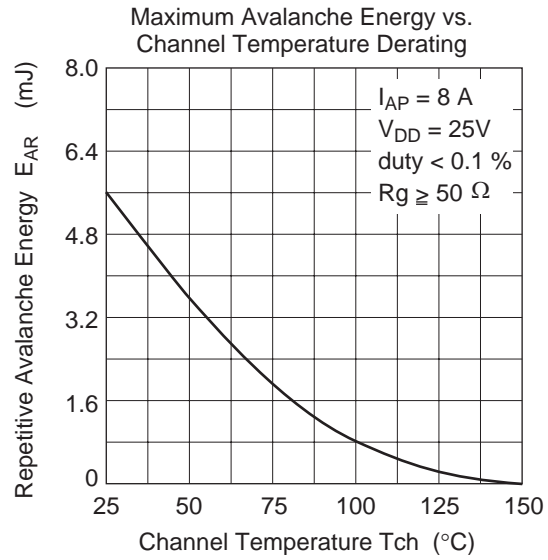
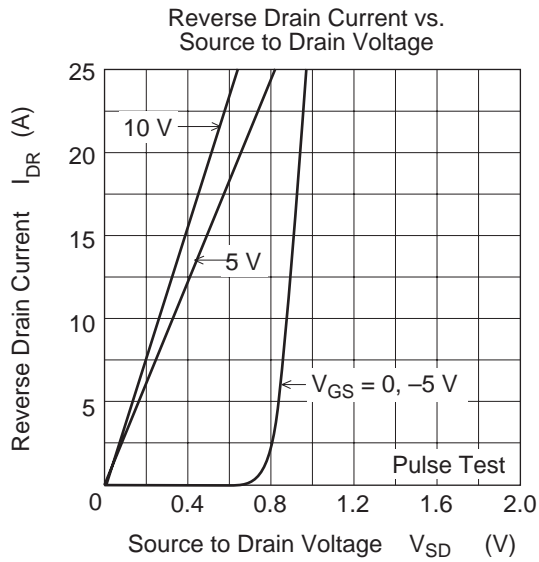
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source break down voltage	$V_{(BR)DSS}$	60	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	$\pm 20$	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 10$	$\mu\text{A}$	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	10	$\mu\text{A}$	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cut off voltage	$V_{GS(off)}$	1.5	—	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	26	34	$\text{m}\Omega$	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
		—	40	56	$\text{m}\Omega$	$I_D = 10 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	$ y_{fs} $	11	18	—	S	$I_D = 10 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	$C_{iss}$	—	1100	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	$C_{oss}$	—	160	—	pF	$V_{GS} = 0$
Reverse transfer admittance	$C_{rss}$	—	90	—	pF	$f = 1 \text{ MHz}$
Total gate charge	$Q_g$	—	21	—	nC	$V_{DD} = 10 \text{ V}$
Gate to source charge	$Q_{gs}$	—	4	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	5	—	nC	$I_D = 20 \text{ A}$
Turn-off delay time	$t_{d(on)}$	—	20	—	ns	$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$
Rise time	$t_r$	—	90	—	ns	$R_L = 3.0 \Omega$
Body-drain diode forward voltage	$t_{d(off)}$	—	65	—	ns	$R_g = 4.7 \Omega$
Fall time	$t_f$	—	15	—	ns	
Body-drain diode forward voltage	$V_{DF}$	—	0.93	—	V	$I_F = 20 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	$t_{rr}$	—	25	—	ns	$I_F = 20 \text{ A}, V_{GS} = 0$ $diF / dt = 100 \text{ A} / \mu\text{s}$

Notes: 4. Pulse test

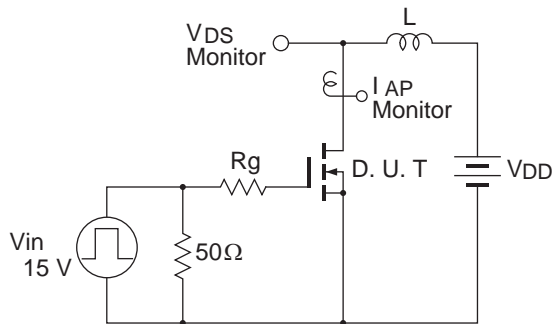
Main Characteristics





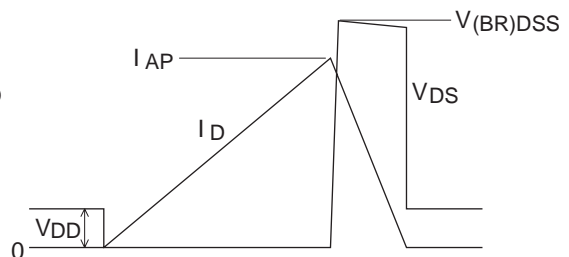


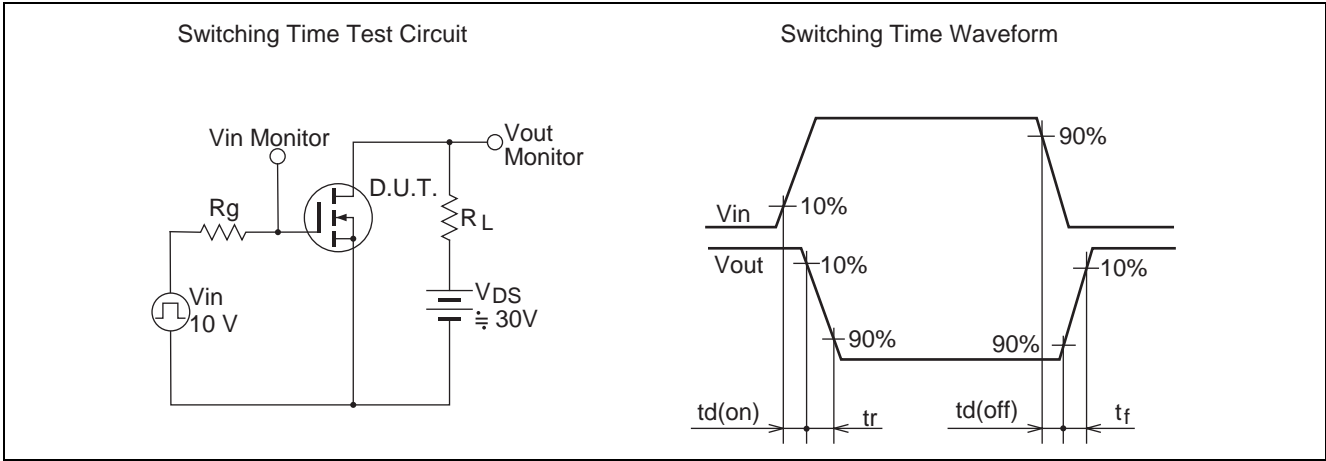
Avalanche Test Circuit



Avalanche Waveform

$$E_{AR} = \frac{1}{2} \cdot L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$

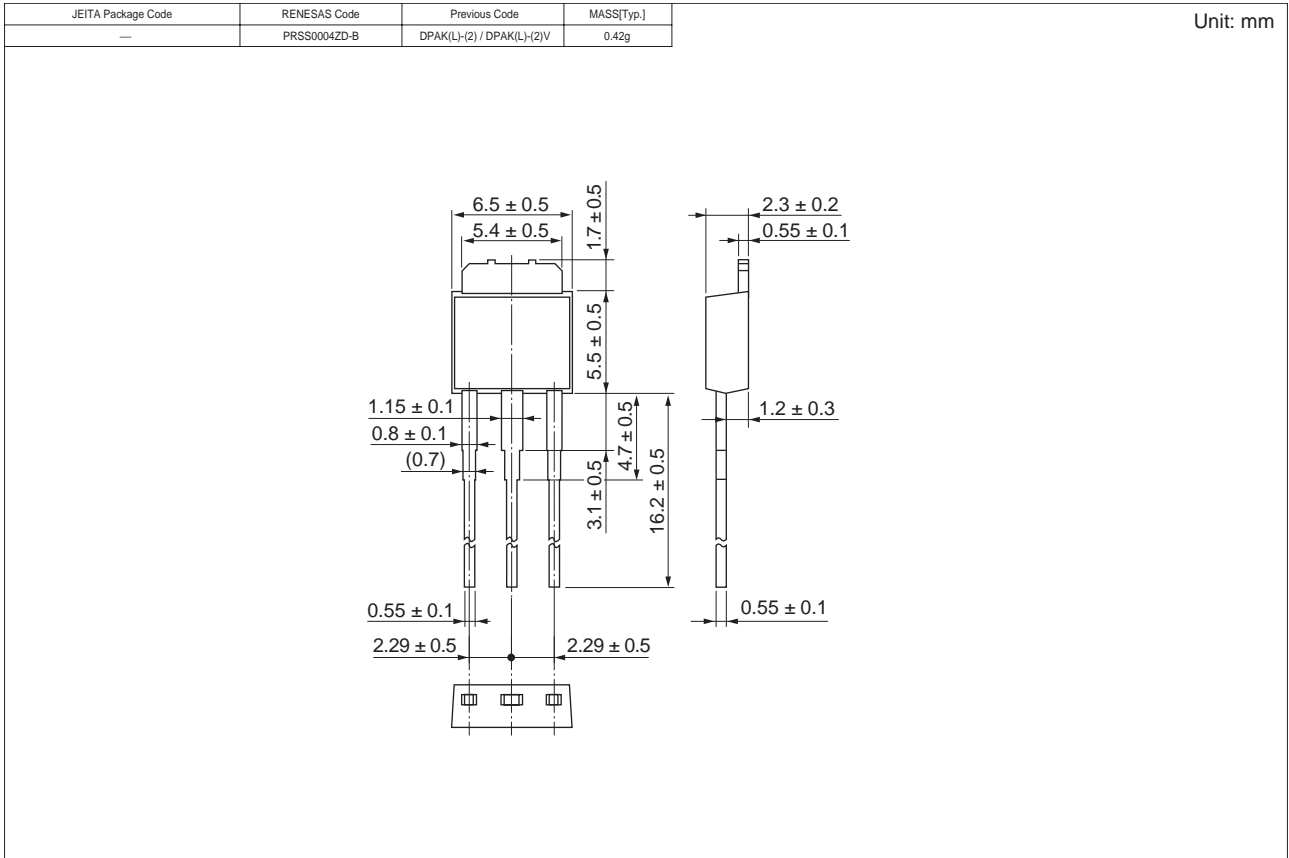




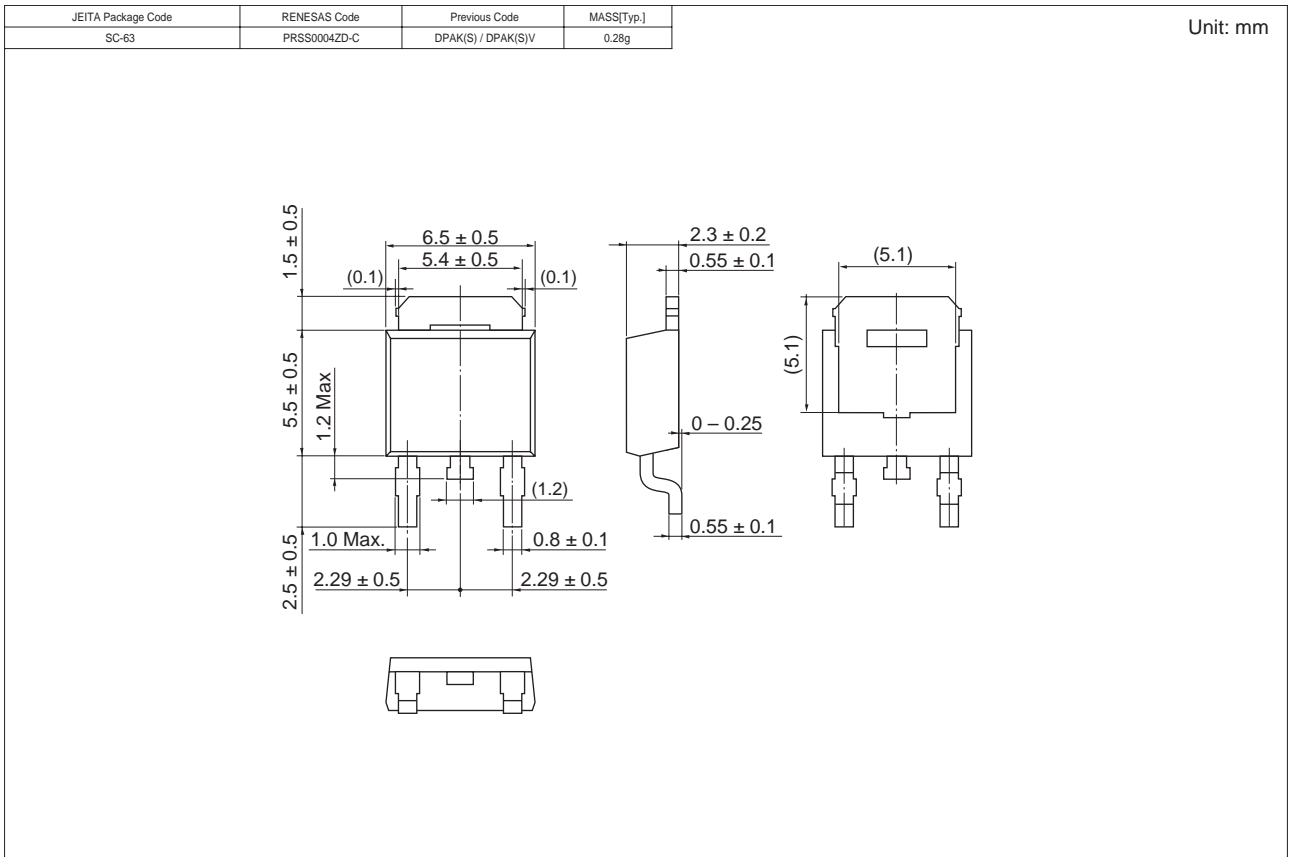


### Package Dimensions

• H7N0607DL



• H7N0607DS



### Ordering Information

Part Name	Quantity	Shipping Container
H7N0607DL	100 pcs	Sack
H7N0607DSTL	3000 pcs	Taping
H7N0607DL-E	100 pcs	Sack
H7N0607DSTL-E	3000 pcs	Taping

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